# NSN 5961-01-093-4282

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## Inclosure Material:

Plastic

# Overall Length:

Between 0.635 inches and 0.645 inches

# **Overall Height:**

Between 0.125 inches and 0.135 inches

#### **Overall Width:**

Between 0.495 inches and 0.505 inches

## Mounting Facility Quantity:

1

# Internal Configuration:

Junction contact

#### **Mounting Method:**

Unthreaded hole

#### Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

300.0 breakdown voltage, collector-to-emitter, base open and 3.0 breakdown voltage, emitter-to-base, collector open

## **Current Rating Per Characteristic:**

500.00 milliamperes source cutoff current

# Power Rating Per Characteristic:

20.0 watts small-signal input power, common-collector

## Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

#### **Special Features:**

Junction pattern arrangement: npn

## **Terminal Type And Quantity:**

3 uninsulated wire lead

Shelf Life:

N/a

#### Unit Of Measure:

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Demilitarization:

No

Fiig:

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